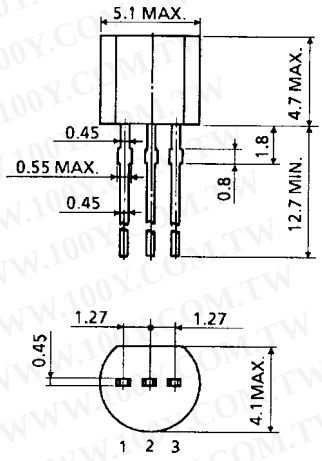
TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT process)

2SC1959

Audio Frequency Low Power Amplifier Applications
Driver Stage Amplifier Applications
Switching Applications

- Excellent h_{FE} linearity: $h_{FE\ (2)}$ = 25 (min): V_{CE} = 6 V, I_C = 400 mA
- 1 watt amplifier applications.
- Complementary to 2SA562TM.

Unit: mm



1. EMITTER
2. COLLECTOR
3. BASE

JEDEC	TO-92
JEITA	SC-43
TOSHIBA	2-5F1B

Weight: 0.21 g (typ.)

Maximum Ratings (Ta = 25°C)

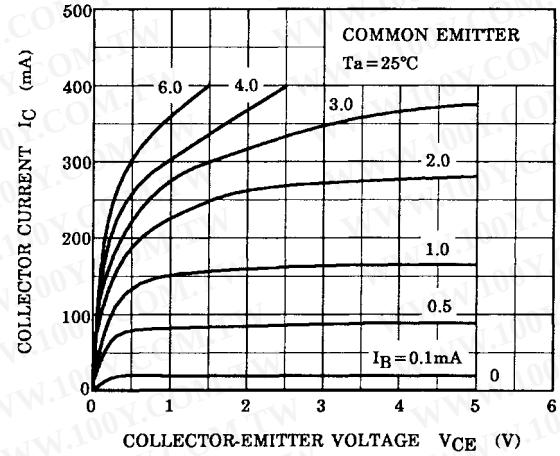
Characteristics	Symbol	Rating	Unit
Collector-base voltage	V_{CBO}	35	V
Collector-emitter voltage	V_{CEO}	30	V
Emitter-base voltage	V_{EBO}	5	V
Collector current	I_C	500	mA
Base current	I_B	100	mA
Collector power dissipation	P_C	500	mW
Junction temperature	T_j	150	°C
Storage temperature range	T_{stg}	−55~150	°C

Electrical Characteristics (Ta = 25°C)

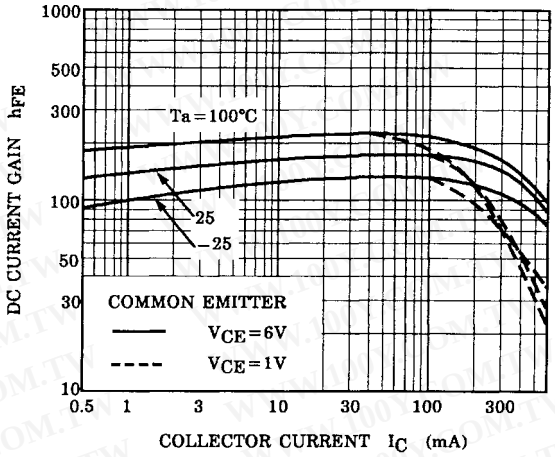
Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	I_{CBO}	V_{CB} = 35 V, I_E = 0	—	—	0.1	μA
Emitter cut-off current	I_{EBO}	V_{EB} = 5 V, I_C = 0	—	—	0.1	μA
DC current gain	$h_{FE\ (1)}$ (Note)	V_{CE} = 1 V, I_C = 100 mA	70	—	400	
	$h_{FE\ (2)}$ (Note)	V_{CE} = 6 V, I_C = 400 mA	25	—	—	
Collector-emitter saturation voltage	$V_{CE\ (sat)}$	I_C = 100 mA, I_B = 10 mA	—	0.1	0.25	V
Base-emitter voltage	V_{BE}	V_{CE} = 1 V, I_C = 100 mA	—	0.8	1.0	V
Transition frequency	f_T	V_{CE} = 6 V, I_C = 20 mA	—	300	—	MHz
Collector output capacitance	C_{ob}	V_{CB} = 6 V, I_E = 0, f = 1 MHz	—	7	—	pF

Note: $h_{FE\ (1)}$ classification O: 70~140, Y: 120~240, GR: 200~400
$h_{FE\ (2)}$ classification O: 25 (min), Y: 40 (min)

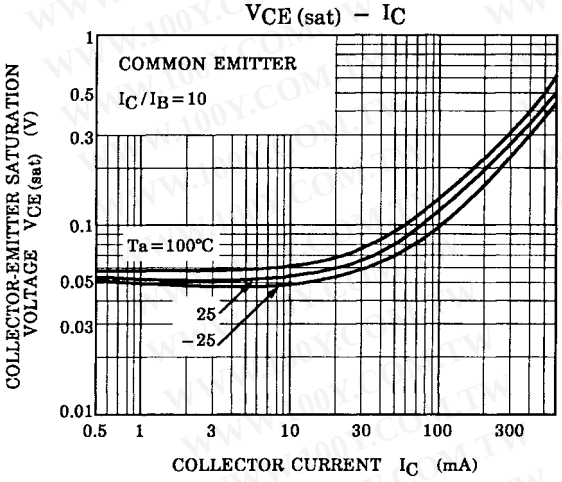
I_C – V_{CE}



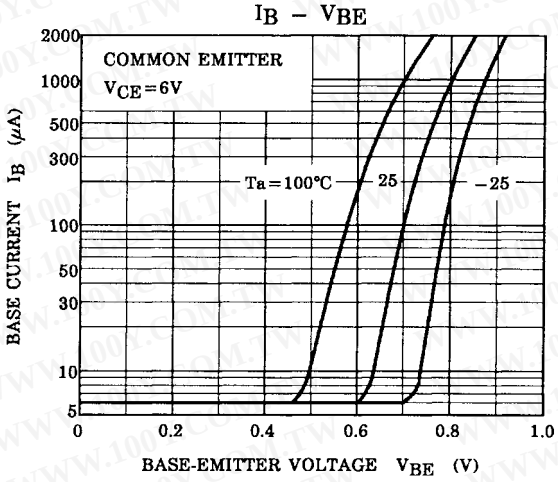
h_{FE} – I_C



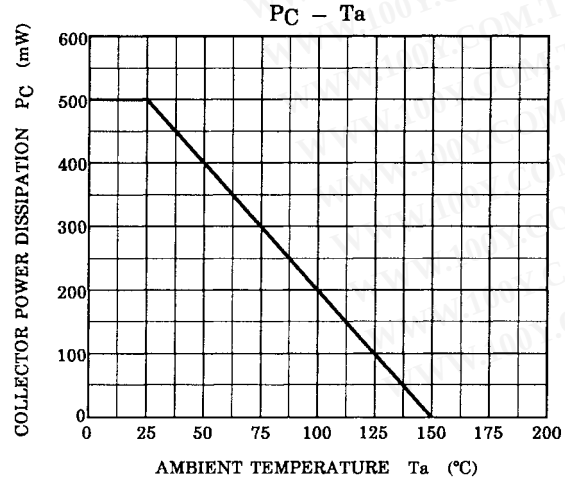
$V_{CE\,(sat)}$ – I_C



I_B – V_{BE}



P_C – Ta



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